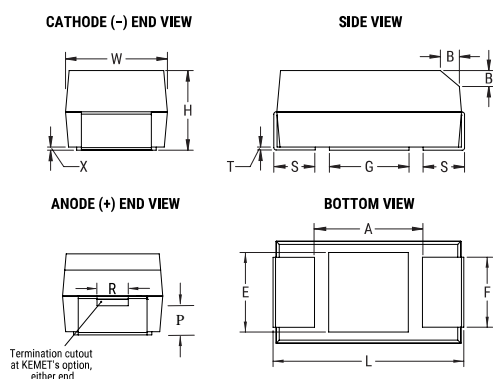


T495, Tantalum, MnO2 Tantalum, 10 uF, 10%, 35 VDC, SMD, MnO2, Molded, Low ESR, 120 mOhms, 7343, Height Max = 3.1mm



## General Information

<b>Series:</b>	T495
<b>Dielectric:</b>	MnO2 Tantalum
<b>Style:</b>	SMD Chip
<b>Description:</b>	SMD, MnO2, Molded, Low ESR
<b>Features:</b>	Low ESR
<b>RoHS:</b>	Yes
<b>Termination:</b>	Tin
<b>AEC-Q200:</b>	No
<b>Shelf Life:</b>	156 Weeks
<b>MSL:</b>	1

## Dimensions

<b>Footprint</b>	7343
<b>L</b>	7.3mm +/-0.3mm
<b>W</b>	4.3mm +/-0.3mm
<b>H</b>	2.8mm +/-0.3mm
<b>T</b>	0.13mm REF
<b>S</b>	1.3mm +/-0.3mm
<b>F</b>	2.4mm +/-0.1mm
<b>A</b>	3.6mm MIN
<b>B</b>	0.5mm +/-0.15mm
<b>E</b>	3.5mm REF
<b>G</b>	3.5mm REF
<b>P</b>	0.9mm REF
<b>R</b>	1mm REF
<b>X</b>	0.1mm +/-0.1mm

## Specifications

<b>Capacitance:</b>	10 uF
<b>Capacitance Tolerance:</b>	10%
<b>Voltage DC:</b>	35 VDC (85C), 23.45 VDC (125C)
<b>Temperature Range:</b>	-55/+125°C
<b>Rated Temperature:</b>	85°C
<b>Dissipation Factor:</b>	4% 120Hz 20C
<b>Failure Rate:</b>	N/A
<b>Resistance:</b>	120 mOhms (100kHz)
<b>Ripple Current:</b>	1118 mA (rms, 100kHz 25C), 1006.2 mA (rms, 85C), 447.2 mA (rms, 125C)
<b>Leakage Current:</b>	3.5 uA (5min 20°C)

## Packaging Specifications

<b>Weight:</b>	446.84 mg
<b>Packaging:</b>	T&R, 178mm
<b>Packaging Quantity:</b>	500